

Substitute form 1449A/PTO

**INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

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Application Number: 10/790,572

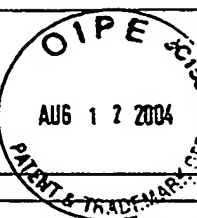
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First Named Inventor: Moon-Sook Lee

Group Art Unit: 2815

Examiner Name: Unknown *A. Wilson*

Attorney Docket Number: 5649-1267



U.S. PATENTS AND PATENT PUBLICATIONS					
Examiner Initials*	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code (if known)		
		US-			
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FOREIGN PATENT DOCUMENTS						
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OTHER NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T
<i>all</i>	1.	Maozzami, R, et al., "Integration of Ferroelectric Capacitor Technology with CMOS", 1994 Symposium on VLSI Technology Digest of Technical Papers, IEEE, 1994, pp. 55-56. <i>No MONTH CITED</i>	
<i>all</i>	2.	Tatsumi Sumi et al., "FA 16.2: A 256kb Nonvolatile Ferroelectric Memory at 3V and 100ns", 1994 IEEE International Solid State Circuits Conference, pp. 268-269. <i>Feb. 1994</i>	

Examiner Signature: *D. R. Hill* Date Considered: *12/12/05*

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.